NSN 5961-01-016-5409

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-016-5409 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.250 inches **Overall Diameter:** Between 0.108 inches and 0.140 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-14 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 8.0 reverse voltage, instantaneous and 9.1 regulator voltage **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current horsepower metric and 0.01 microamperes forward current, average peak **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No